

### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 2. Features and benefits

- Logic-level compatible
- Trench MOSFET technology
- · Ultra low Q<sub>G</sub> and Q<sub>GD</sub> for high system efficiency, especially at higher switching frequencies
- Superfast switching with soft-recovery
- Low spiking and ringing for low EMI designs
- MLPAK33 package (3.3 x 3.3 mm footprint)

#### 3. Applications

- DC to DC conversion
- Battery management
- Low-side load switch
- Switching circuits

#### 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	25	V
V <sub>GS</sub>	gate-source voltage			-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-	19	А
Static chara	acteristics						
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 11.8 A; T <sub>j</sub> = 25 °C		-	6.6	7.7	mΩ
	resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 9.8 A; T <sub>j</sub> = 25 °C		-	8.9	11.1	mΩ
Dynamic ch	naracteristics			·			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 12.5 V; I <sub>D</sub> = 9.8 A; V <sub>GS</sub> = 4.5 V; T <sub>j</sub> = 25 °C		-	5.3	8	nC

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

# nexperia

# 5. Pinning information

Table 2	able 2. Pinning information						
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	S	source	1 2 3 4				
2	S	source	رففف م				
3	S	source		D			
4	G	gate	Ę ₽				
5	D	drain		G L H A			
6	D	drain	Церей	mbb076 S			
7	D	drain					
8	D	drain	MLPAK33 (SOT8002-1)				

# 6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
PXN7R7-25QL		plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1		

# 7. Marking

Table 4. Marking codes	
Type number	Marking code
PXN7R7-25QL	9AE

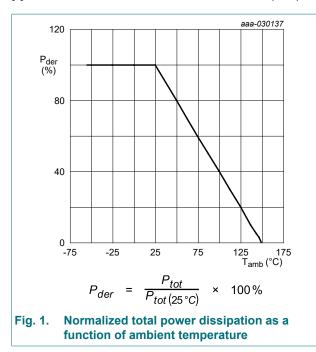
#### 8. Limiting values

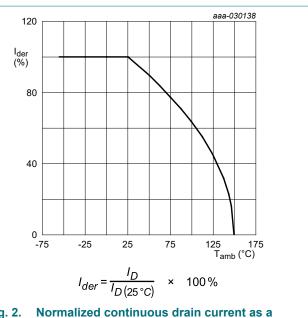
#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	25	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
ID	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	19	А
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	11.8	А
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 100 °C	[1]	-	7.5	А
		V <sub>GS</sub> = 10 V; T <sub>sp</sub> = 25 °C		-	32	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	102	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	4.3	W
		T <sub>amb</sub> = 25 °C	[1]	-	1.7	W
		T <sub>sp</sub> = 25 °C		-	12.5	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drain di	ode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	1.5	А
Avalanche rugg	jedness	•				
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	T <sub>j(init)</sub> = 25 °C; I <sub>D</sub> = 1.8 A; DUT in avalanche (unclamped)		-	22.5	mJ

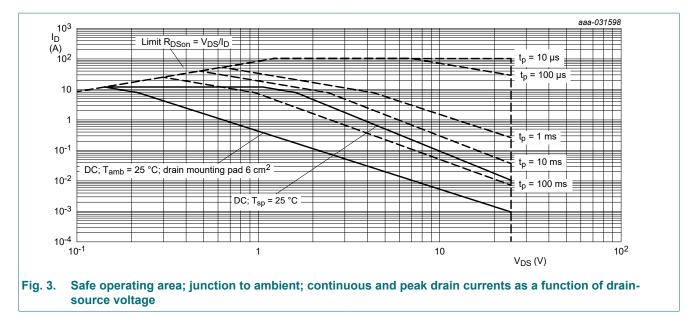
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.







#### 25 V, N-channel Trench MOSFET



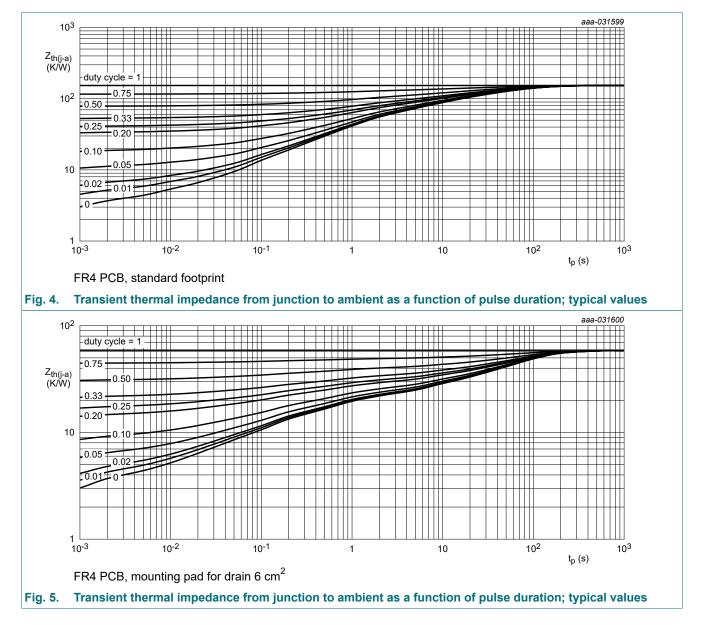
PXN7R7-25QL

### 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	150	190	K/W
			[2]	-	60	75	K/W
		in free air; t ≤ 5 s	[2]	-	24	29	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	7	10	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

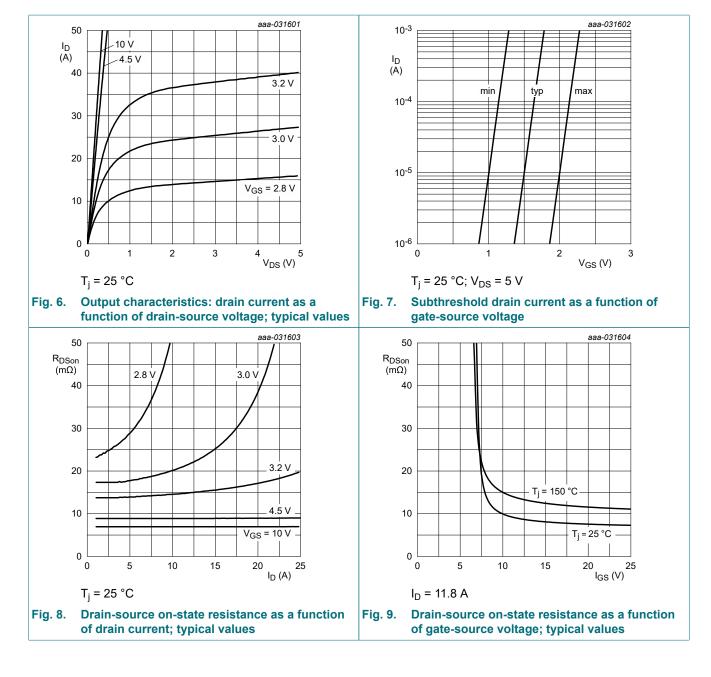
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



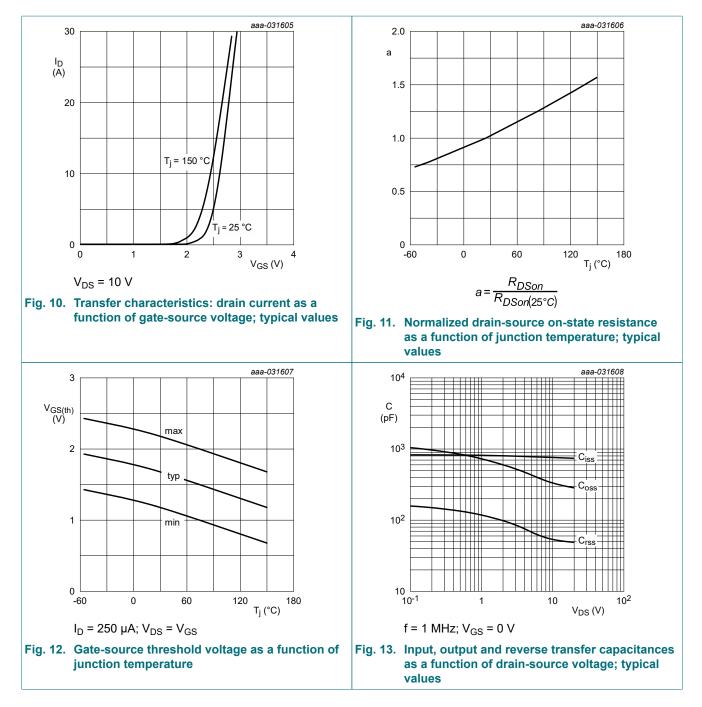
# **10. Characteristics**

$\begin{array}{ c c c c c c } \hline V_{DS} & V_{DS} & V_{DS} & V_{CS} & V_{CS} & V_{CS} & V_{T} & V_{DS} & V_{DS} & V_{T} & V_{DS} & V_{DS$	7 2.2 1 0.1 -0.1 0.6 7.7 0.2 11.9 0.9 11.1 25 - 2.3 - 1.1 16.6 5.3 8	V μΑ μΑ μΑ mΩ mΩ S Ω
breakdown voltage         Image: Normal and the second secon	1           0.1           -0.1           5.6         7.7           0.2         11.9           5.9         11.1           25         -           2.3         -           1.1         16.6	V μΑ μΑ mΩ mΩ S Ω
voltage         <	1           0.1           -0.1           5.6         7.7           0.2         11.9           5.9         11.1           25         -           2.3         -           1.1         16.6	μΑ μΑ μΑ mΩ mΩ S Ω
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	0.1           -0.1           6.6         7.7           0.2         11.9           8.9         11.1           25         -           2.3         -           1.1         16.6	μΑ μΑ mΩ mΩ mΩ S
$ \begin{array}{ c c c c c } \hline V_{GS} = -20 \ V; \ V_{DS} = 0 \ V; \ T_{j} = 25 \ ^{\circ}C & & & - & - & - & - & - & - & - & - & $	-0.1 5.6 7.7 0.2 11.9 5.9 11.1 5.5 - 2.3 - 1.1 16.6	μΑ mΩ mΩ mΩ S
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	0.6     7.7       0.2     11.9       0.9     11.1       25     -       2.3     -       1.1     16.6	mΩ mΩ mΩ S
$ \begin{array}{ c c c c c c c } \hline resistance & \hline V_{GS} = 10 \ V; \ I_D = 11.8 \ A; \ T_j = 150 \ ^{\circ}C & - & 1 \\ \hline V_{GS} = 4.5 \ V; \ I_D = 9.8 \ A; \ T_j = 25 \ ^{\circ}C & - & 8 \\ \hline V_{DS} = 10 \ V; \ I_D = 11.8 \ A; \ T_j = 25 \ ^{\circ}C & - & 2 \\ \hline P_{GS} & gate resistance & f = 1 \ MHz & - & 2 \\ \hline Dynamic characteristics & & & & & & & & & & & & & & & & & & &$	0.2     11.9       9.9     11.1       25     -       2.3     -       1.1     16.6	mΩ mΩ S Ω
$ \frac{V_{GS} = 10 \text{ V}, \text{ I}_D = 11.8 \text{ A}, \text{ I}_j = 130 \text{ C} \qquad - \qquad 8 \\ V_{GS} = 4.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ T}_j = 25 ^{\circ}\text{C} \qquad - \qquad 8 \\ V_{DS} = 4.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ T}_j = 25 ^{\circ}\text{C} \qquad - \qquad 2 \\ V_{DS} = 10 \text{ V}; \text{ I}_D = 11.8 \text{ A}; \text{ T}_j = 25 ^{\circ}\text{C} \qquad - \qquad 2 \\ \hline \text{Dynamic characteristics} \qquad - \qquad 2 \\ \hline \text{Dynamic characteristics} \qquad - \qquad 2 \\ \hline \text{Q}_{G(tot)} \qquad total gate charge} \qquad V_{DS} = 12.5 \text{ V}; \text{ I}_D = 11.8 \text{ A}; \text{ V}_{GS} = 10 \text{ V}; \\ T_j = 25 ^{\circ}\text{C} \qquad - \qquad 1 \\ \hline V_{DS} = 12.5 \text{ V}; \text{ I}_D = 11.8 \text{ A}; \text{ V}_{GS} = 10 \text{ V}; \\ T_j = 25 ^{\circ}\text{C} \qquad - \qquad 5 \\ \hline \text{V}_{DS} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \qquad - \qquad 5 \\ \hline \text{Q}_{GS} \qquad \text{gate-source charge} \qquad - \qquad 2 \\ \hline \text{Q}_{GS(th)} \qquad \text{pre-threshold gate-source charge} \qquad - \qquad 2 \\ \hline \text{Q}_{GS(th-pl)} \qquad \text{post-threshold gate-source charge} \qquad - \qquad 1 \\ \hline \text{Dote charge} \qquad - \qquad 1 \\ \hline \text{D}_{S} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \qquad - \qquad 5 \\ \hline \text{D}_{S} = 25 ^{\circ}\text{C} \qquad - \qquad 2 \\ \hline \text{D}_{S} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \qquad - \qquad 5 \\ \hline \text{D}_{S} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \qquad - \qquad 1 \\ \hline \text{D}_{S} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \qquad - \qquad 1 \\ \hline \text{D}_{S} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \qquad - \qquad 1 \\ \hline \text{D}_{S} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \qquad - \qquad 2 \\ \hline \text{D}_{S} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \qquad - \qquad 1 \\ \hline \text{D}_{S} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \qquad - \qquad 1 \\ \hline \text{D}_{S} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ I}_D = 9.8$	9.9     11.1       25     -       2.3     -       1.1     16.6	mΩ S Ω
$g_{fs}$ forward transconductance $V_{DS} = 10 \text{ V}; \text{ I}_D = 11.8 \text{ A}; \text{ T}_j = 25 ^{\circ}\text{C}$ -2 $R_G$ gate resistance $f = 1 \text{ MHz}$ -2Dynamic characteristics $Q_G(tot)$ total gate charge $V_{DS} = 12.5 \text{ V}; \text{ I}_D = 11.8 \text{ A}; \text{ V}_{GS} = 10 \text{ V};$ $T_j = 25 ^{\circ}\text{C}$ -1 $Q_{G(tot)}$ total gate charge $V_{DS} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V};$ $T_j = 25 ^{\circ}\text{C}$ -5 $Q_{GS}$ gate-source charge $T_j = 25 ^{\circ}\text{C}$ -5 $Q_{GS(th)}$ pre-threshold gate- source charge-1 $Q_{GS(th-pl)}$ post-threshold gate- source charge-0	25 - 2.3 - 1.1 16.6	S Ω
$ \begin{array}{c c c c c c c } \hline transconductance & f = 1 \ MHz & - \ 2 \\ \hline \textbf{Dynamic characteristics} \\ \hline \textbf{Q}_{G(tot)} & total gate charge & V_{DS} = 12.5 \ V; \ \textbf{I}_{D} = 11.8 \ A; \ V_{GS} = 10 \ V; \\ \hline \textbf{T}_{j} = 25 \ ^{\circ}C & V_{DS} = 12.5 \ V; \ \textbf{I}_{D} = 9.8 \ A; \ V_{GS} = 4.5 \ V; & - \ 5 \\ \hline \textbf{V}_{DS} = 12.5 \ V; \ \textbf{I}_{D} = 9.8 \ A; \ V_{GS} = 4.5 \ V; & - \ 5 \\ \hline \textbf{T}_{j} = 25 \ ^{\circ}C & - \ 2 \\ \hline \textbf{Q}_{GS(th)} & pre-threshold gate-source charge \\ \hline \textbf{Q}_{GS(th-pl)} & post-threshold gate-source cha$	2.3 - 1.1 16.6	Ω
Operation of the second secon	1.1 16.6	
Dynamic characteristics $Q_{G(tot)}$ total gate charge $V_{DS} = 12.5 \text{ V}; \text{ I}_D = 11.8 \text{ A}; \text{ V}_{GS} = 10 \text{ V}; \\ T_j = 25 \ ^{\circ}\text{C}$ -1 $V_{DS} = 12.5 \text{ V}; \text{ I}_D = 9.8 \text{ A}; \text{ V}_{GS} = 4.5 \text{ V}; \\ Q_{GS}$ gate-source charge-5 $Q_{GS(th)}$ pre-threshold gate-source charge-2 $Q_{GS(th-pl)}$ post-threshold gate-source charge-1		
$ \begin{array}{c c} Q_{G(tot)} \\ Q_{G(tot)} \\ Q_{G(tot)} \\ Q_{GS(tot)} \\ Q_{GS} \\ Q_{GS} \\ Q_{GS(th)} \\ Q_{GS(th-pl)} \\ Q_{GS(th-pl)} \\ \end{array} \begin{array}{c c} total gate charge \\ gate - source charge \\ Q_{GS(th-pl)} \\ post-threshold gate - source charge \\ Source charge \\ \end{array} \begin{array}{c c} V_{DS} = 12.5 \ V; \ I_D = 11.8 \ A; \ V_{GS} = 10 \ V; \\ T_j = 25 \ ^{\circ}C \\ \hline V_{DS} = 12.5 \ V; \ I_D = 9.8 \ A; \ V_{GS} = 4.5 \ V; \\ T_j = 25 \ ^{\circ}C \\ \hline T_j = 25 \ ^{}$		
$Q_{GS}$ gate-source charge $T_j = 25 \ ^{\circ}C$ -2 $Q_{GS(th)}$ pre-threshold gate- source charge-1 $Q_{GS(th-pl)}$ post-threshold gate- source charge-0	3 8	nC
QGS     gate-source charge       QGS(th)     pre-threshold gate- source charge       QGS(th-pl)     post-threshold gate- source charge	0.5	nC
Q <sub>GS(th-pl)</sub> post-threshold gate- source charge     -     0	2 -	nC
source charge	.2 -	nC
	0.8 -	nC
Q <sub>GD</sub> gate-drain charge - 1	.5 -	nC
$V_{GSpl}$ gate-source plateau $V_{DS}$ = 12.5 V; $I_D$ = 9.8 A; $T_j$ = 25 °C - 2 voltage	2.8 -	V
	70 -	pF
$C_{oss}$ output capacitance $T_j = 25 \ ^{\circ}C$ - 3	- 10	pF
C <sub>rss</sub> reverse transfer - 5 capacitance	5 -	pF
$t_{d(on)}$ turn-on delay time $V_{DS}$ = 12.5 V; $I_D$ = 9.8 A; $V_{GS}$ = 4.5 V; - 5	; -	ns
$R_{G(ext)} = 5 \Omega; T_j = 25 °C$ - 8	; -	ns
t <sub>d(off)</sub> turn-off delay time - 6	; -	ns
t <sub>f</sub> fall time - 3	; -	ns
Source-drain diode		1
$V_{SD}$ source-drain voltage $I_S = 1.5 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ - 0	0.7 1.2	V
$I_{rr}$ reverse recovery time $I_S = 1.5 \text{ A}$ ; $dI_S/dt = -100 \text{ A}/\mu \text{s}$ ; - 1	5 -	ns
$Q_r$ recovered charge $V_{GS} = 4.5 \text{ V}; V_{DS} = 12.5 \text{ V}; T_j = 25 ^{\circ}\text{C}$ - 6	; -	nC
t <sub>a</sub> reverse recovery rise time - 8	; -	ns
t <sub>b</sub> reverse recovery fall time - 7		ns

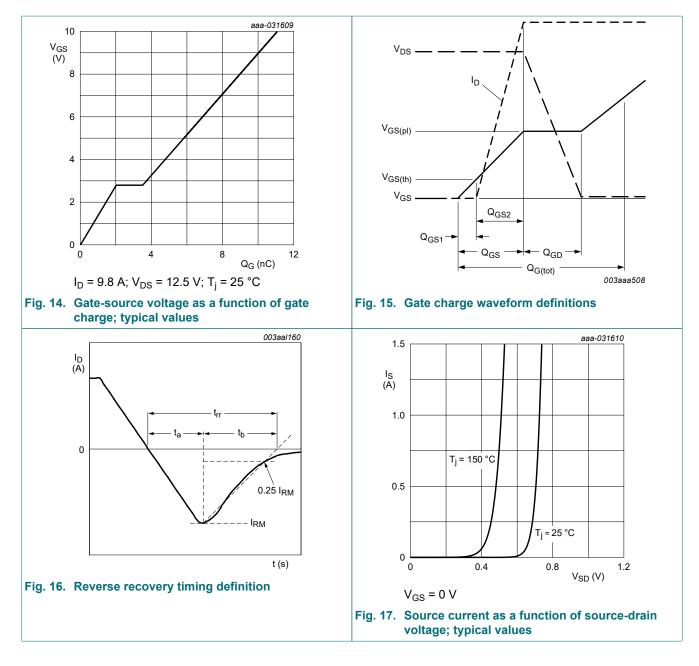
#### 25 V, N-channel Trench MOSFET



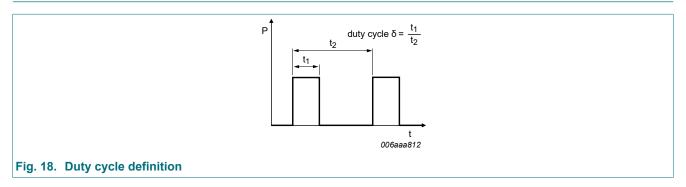
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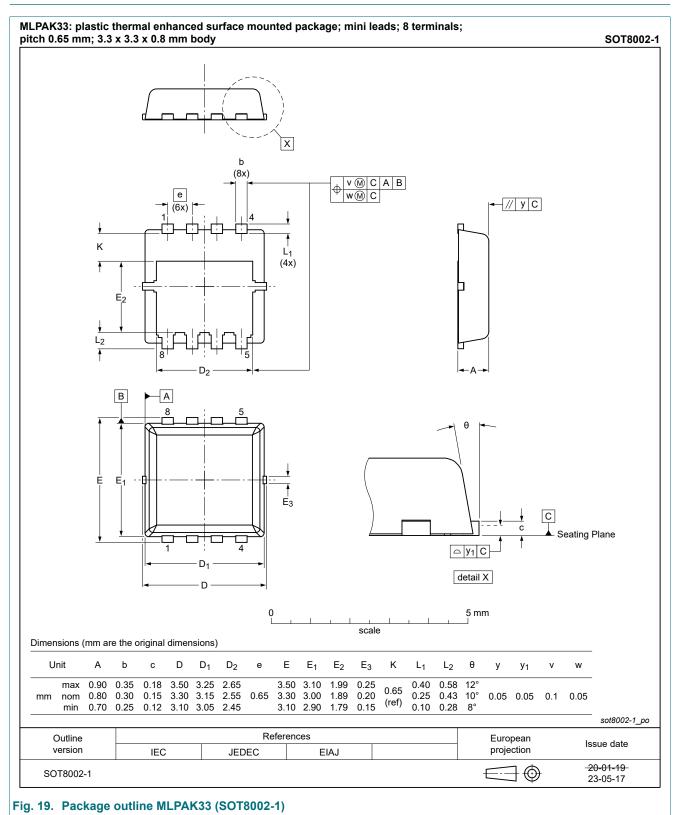
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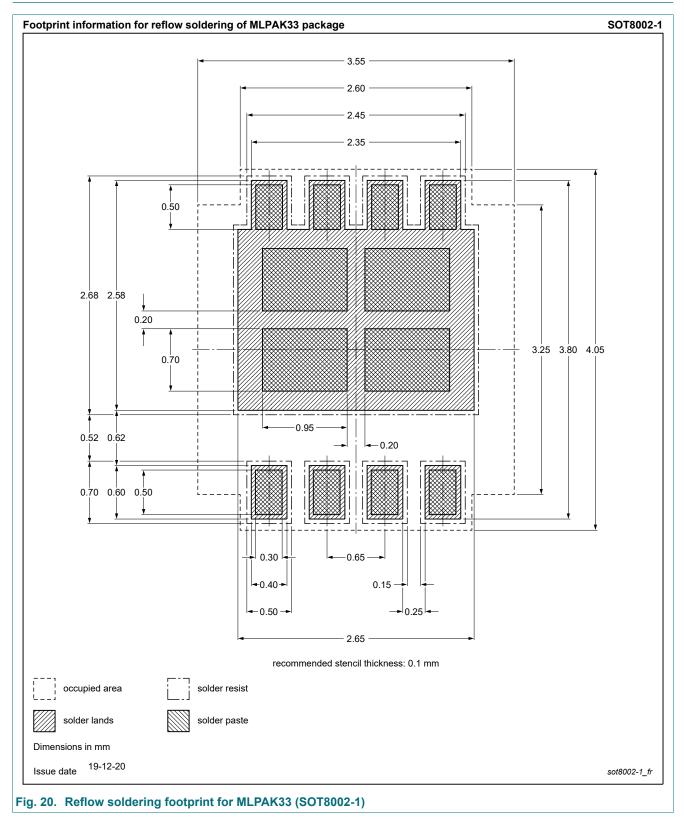
#### 11. Test information



#### 12. Package outline



### 13. Soldering



# 14. Revision history

Table 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PXN7R7-25QL v.2	20230731	Product data sheet	-	PXN7R7-25QL v.1	
Modifications:	Chapter "Package or	utline": drawing update			
PXN7R7-25QL v.1	20201102	Product data sheet	-	-	

PXN7R7-25QL

### 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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### Contents

1.	General description	. 1
2.	Features and benefits	. 1
3.	Applications	. 1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	. 2
8.	Limiting values	. 3
9.	Thermal characteristics	. 5
10.	Characteristics	. 6
11.	Test information	. 9
12.	Package outline	10
13.	Soldering	11
14.	Revision history	12
15.	Legal information	13

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